

INFORMATION DISCLOSURE CITATION
(Use several sheets if necessary)



Docket Number (Optional)
K06-223706/TBS

Application Number 10/589,852
UNKNOWN

Applicant(s)
Joel KUSTER, et al.

Filing Date 08/17/2006
Concurrently Herewith

Group Art Unit
Unknown 4176

PATENT DOCUMENTS

EXAMINER INITIAL	REF	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE

U.S. PATENT APPLICATION PUBLICATIONS

EXAMINER INITIAL	REF	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
/D.W./		2003/0107098	06/12/2003	Ota, et al.			
/D.W./		2004/0007708	01/15/2004	Inchinose, et al.			

FOREIGN PATENT DOCUMENTS

REF	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	Translation	
						YES	NO

OTHER DOCUMENTS

(Including Author, Title, Date, Pertinent Pages, Etc.)

/D.W./		International Search Report dated April 26, 2005
/D.W./		Harwig, T. et al., "ELECTRICAL PROPERTIES OF B-Ga2O3 SINGLE CRYSTALS", In: Solid State Communication 1976, Vol. 18, pages 1223 to 1225

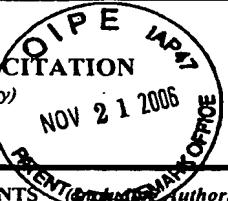
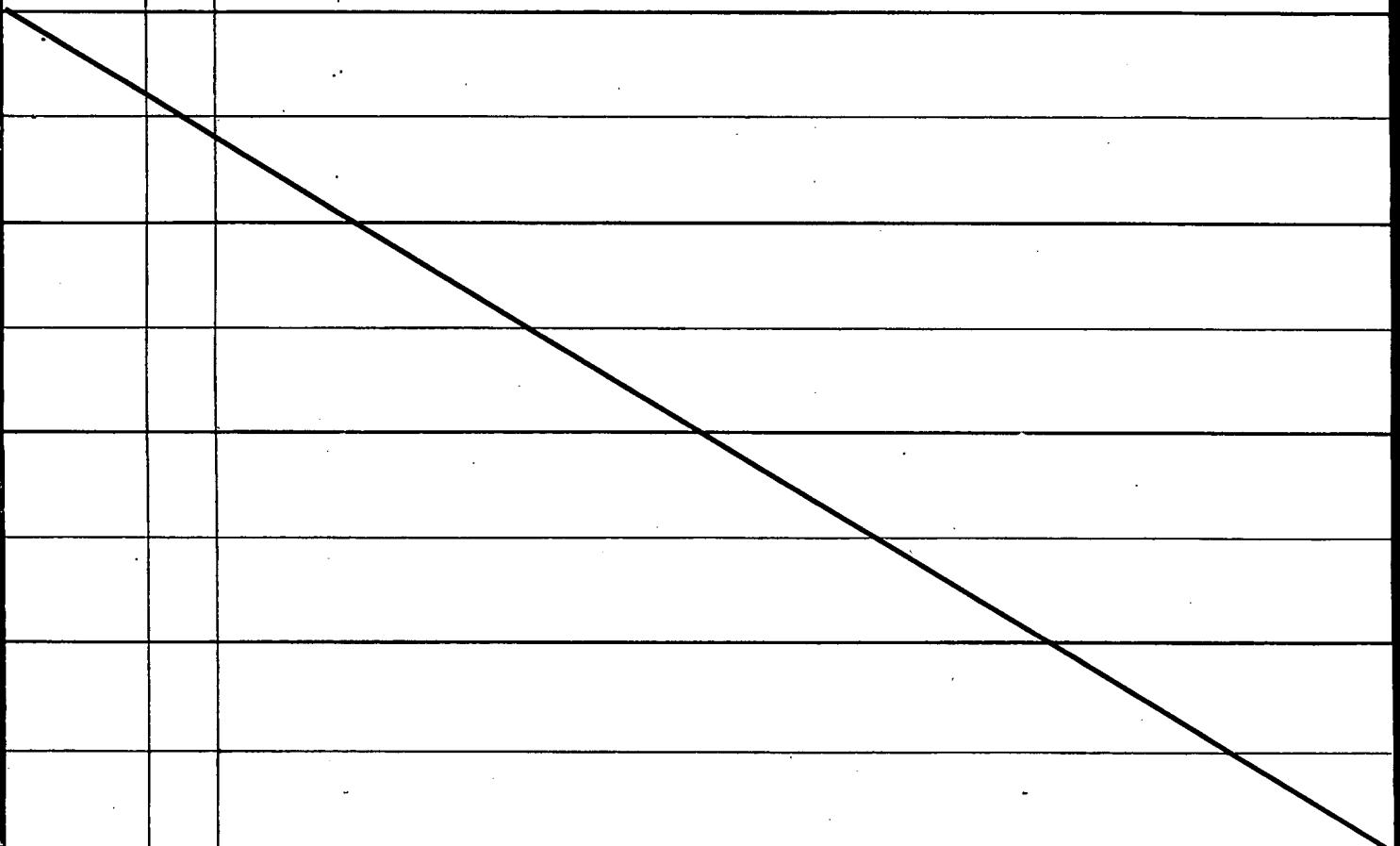
EXAMINER

/Daniel Whalen/

DATE CONSIDERED

10/18/2007

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP Section 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

INFORMATION DISCLOSURE CITATION <i>(Use several sheets if necessary)</i>		Docket Number (Optional) PKHF-05004 US	Application Number 10/589,852
		Applicant(s) Noboru ICHINOSE	
		Filing Date August 17, 2006	Group Art Unit 4176 <i>Not Yet Assigned</i>
*EXAMINER INITIAL	OTHER DOCUMENTS <i>(Author, Title, Date, Pertinent Pages, Etc.)</i>		
/D.W./	UEDA, N. et al., "SYNTHESIS AND CONTROL OF CONDUCTIVITY OF ULTRAVIOLET TRANSMITTING B-Ga ₂ O ₃ SINGLE CRYSTALS", in: Applied Physics Letters, June, 30, 1997, Vol.70, Issue 26, pages 3561 to 3563		
/D.W./	TOMM, Y. et al., "FLOATING ZONE GROWTH OF B-Ga ₂ O ₃ : A NEW WINDOW MATERIAL FOR OPTOELECTRONIC DEVICE APPLICATIONS", In: Solar Energy Materials & Solar Cells, February, 2001, Vol. 66, pages 369 to 374		
/D.W./	FRANK, J. et al., "ELECTRICAL DOPING OF GAS-SENSITIVE, SEMICONDUCTING Ga ₂ O ₃ THIN FILMS", In: Sensors and Actuators B: Chemical, August 1996, Vol. 34, pages 373 to 377		
/D.W./	HARWIG, T. et al., "ELECTRICAL PROPERTIES OF B-Ga ₂ O ₃ SINGLE CRYSTALS. II", In: Journal of Solid State Chemistry, 15 January, 1978 (15.01.78), Vol. 23, pages 205 to 211		
			
EXAMINER /Daniel Whalen/	DATE CONSIDERED 10/18/2007		
*EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP Section 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.			